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# 1Mb Ultra-Low Power Asynchronous CMOS SRAM $64K \times 16$ bit

#### Overview

The N01L63W2A is an integrated memory device containing a 1 Mbit Static Random Access Memory organized as 65,536 words by 16 bits. ON Semiconductor's advanced CMOS technology to provide both high-speed performance and ultra-low power. The device operates with two chip enable  $(\overline{CE1}$  and CE2) controls and output enable  $(\overline{OE})$  to allow for easy memory expansion. Byte controls  $(\overline{UB} \text{ and } \overline{LB})$  allow the upper and lower bytes to be accessed independently and can also be used to deselect the device. The N01L63W2A is optimal for various applications where low-power is critical such as battery backup and hand-held devices. The device can operate over a very wide temperature range of -40°C to +85°C and is available in JEDEC standard packages compatible with other standard 64Kb x 16 SRAMs.

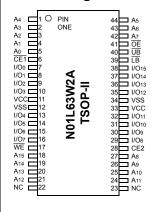
### **Features**

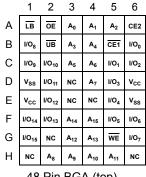
- Single Wide Power Supply Range 2.3 to 3.6 Volts
- Very low standby current 2.0µA at 3.0V (Typical)
- Very low operating current 2.0mA at 3.0V and 1µs (Typical)
- Very low Page Mode operating current 0.8mA at 3.0V and 1µs (Typical)
- Simple memory control Dual Chip Enables (CE1and CE2) Byte control for independent byte operation Output Enable (OE) for memory expansion
- · Low voltage data retention Vcc = 1.8V
- · Very fast output enable access time 30ns OE access time
- Automatic power down to standby mode
- TTL compatible three-state output driver
- · Compact space saving BGA package available

## **Product Family**

Part Number	Package Type	Operating Temperature	Power Supply (Vcc)	Speed	Standby Current (I <sub>SB</sub> ), Typical	Operating Current (Icc), Typical
N01L63W2AB	48 - BGA					
N01L63W2AT	44 - TSOP II	10001	2 2 1/ 2 6 1/	55ns @ 2.7V	2 4	2 m A @ 1MU=
N01L63W2AB2	48 - BGA Green	-40°C to +85°C	2.30 - 3.00	70ns @ 2.3V	2 μΑ	2 mA @ 1MHz
N01L63W2AT2	44 - TSOP II Green					

## **Pin Configuration**

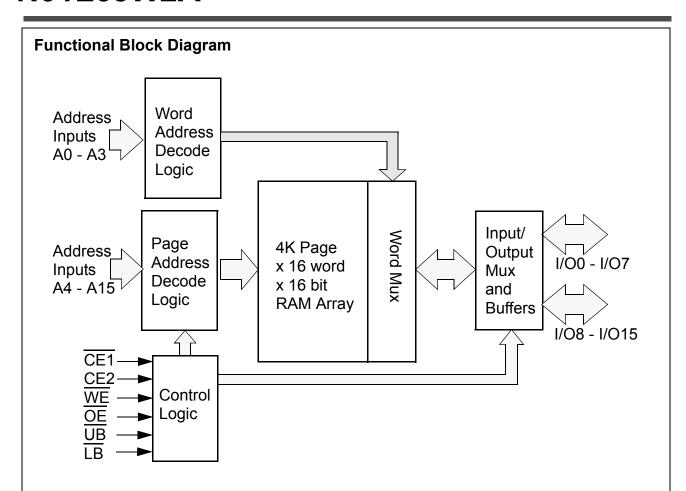




48 Pin BGA (top) 6 x 8 mm

## **Pin Descriptions**

Pin Name	Pin Function
A <sub>0</sub> -A <sub>15</sub>	Address Inputs
WE	Write Enable Input
CE1, CE2	Chip Enable Input
ŌĒ	Output Enable Input
LB	Lower Byte Enable Input
UB	Upper Byte Enable Input
I/O <sub>0</sub> -I/O <sub>15</sub>	Data Inputs/Outputs
V <sub>CC</sub>	Power
V <sub>SS</sub>	Ground
NC	Not Connected



## **Functional Description**

CE1	CE2	WE	OE	UB	LB	I/O <sub>0</sub> - I/O <sub>15</sub> <sup>1</sup>	MODE	POWER
Н	Х	Х	Х	Х	Х	High Z	Standby <sup>2</sup>	Standby
Х	L	Χ	Χ	Χ	Χ	High Z	Standby <sup>2</sup>	Standby
L	Н	Х	Х	Н	Н	High Z	Standby	Standby
L	Н	L	$X^3$	$L^1$	L <sup>1</sup>	Data In	Write <sup>3</sup>	Active
L	Н	Н	L	L <sup>1</sup>	L <sup>1</sup>	Data Out	Read	Active
L	Н	Н	Н	L <sup>1</sup>	L <sup>1</sup>	High Z	Active	Active

<sup>1.</sup> When  $\overline{\text{UB}}$  and  $\overline{\text{LB}}$  are in select mode (low), I/O<sub>0</sub> - I/O<sub>15</sub> are affected as shown. When  $\overline{\text{LB}}$  only is in the select mode only I/O<sub>0</sub> - I/O<sub>7</sub> are affected as shown. When  $\overline{\text{UB}}$  is in the select mode only I/O<sub>8</sub> - I/O<sub>15</sub> are affected as shown.

# Capacitance<sup>1</sup>

Item	Symbol	Test Condition	Min	Max	Unit
Input Capacitance	C <sub>IN</sub>	$V_{IN} = 0V, f = 1 \text{ MHz}, T_A = 25^{\circ}C$		8	pF
I/O Capacitance	C <sub>I/O</sub>	V <sub>IN</sub> = 0V, f = 1 MHz, T <sub>A</sub> = 25°C		8	pF

<sup>1.</sup> These parameters are verified in device characterization and are not 100% tested

<sup>2.</sup> When the device is in standby mode, control inputs ( $\overline{WE}$ ,  $\overline{OE}$ ,  $\overline{UB}$ , and  $\overline{LB}$ ), address inputs and data input/outputs are internally isolated from any external influence and disabled from exerting any influence externally.

<sup>3.</sup> When  $\overline{\text{WE}}$  is invoked, the  $\overline{\text{OE}}$  input is internally disabled and has no effect on the circuit.

## Absolute Maximum Ratings<sup>1</sup>

Item	Symbol	Rating	Unit
Voltage on any pin relative to V <sub>SS</sub>	V <sub>IN,OUT</sub>	-0.3 to V <sub>CC</sub> +0.3	V
Voltage on V <sub>CC</sub> Supply Relative to V <sub>SS</sub>	V <sub>CC</sub>	-0.3 to 4.5	V
Power Dissipation	$P_{D}$	500	mW
Storage Temperature	T <sub>STG</sub>	-40 to 125	°C
Operating Temperature	T <sub>A</sub>	-40 to +85	°C
Soldering Temperature and Time	T <sub>SOLDER</sub>	260°C, 10sec	°C

<sup>1.</sup> Stresses greater than those listed above may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operating section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

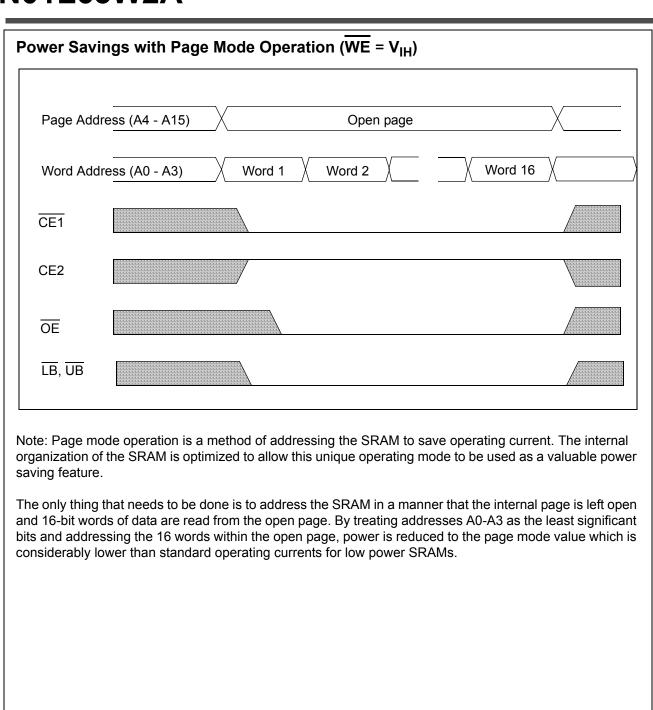
#### **Operating Characteristics (Over Specified Temperature Range)**

Item	Symbol	ool Test Conditions		Typ <sup>1</sup>	Max	Unit
Supply Voltage	V <sub>CC</sub>		2.3	3.0	3.6	V
Data Retention Voltage	$V_{DR}$	Chip Disabled <sup>3</sup>	1.8			V
Input High Voltage	V <sub>IH</sub>		1.8		V <sub>CC</sub> +0.3	V
Input Low Voltage	V <sub>IL</sub>		-0.3		0.6	V
Output High Voltage	V <sub>OH</sub>	I <sub>OH</sub> = 0.2mA	V <sub>CC</sub> -0.2			V
Output Low Voltage	V <sub>OL</sub>	I <sub>OL</sub> = -0.2mA			0.2	V
Input Leakage Current	I <sub>LI</sub>	V <sub>IN</sub> = 0 to V <sub>CC</sub>			0.5	μА
Output Leakage Current	I <sub>LO</sub>	OE = V <sub>IH</sub> or Chip Disabled			0.5	μА
Read/Write Operating Supply Current  @ 1 µs Cycle Time <sup>2</sup>	I <sub>CC1</sub>	$V_{CC}$ =3.6 V, $V_{IN}$ = $V_{IH}$ or $V_{IL}$ Chip Enabled, $I_{OUT}$ = 0		2.0	3.0	mA
Read/Write Operating Supply Current @ 70 ns Cycle Time <sup>2</sup>	I <sub>CC2</sub>	$V_{CC}$ =3.6 V, $V_{IN}$ = $V_{IH}$ or $V_{IL}$ Chip Enabled, $I_{OUT}$ = 0		9.5	14.0	mA
Page Mode Operating Supply Current @ 70ns Cycle Time <sup>2</sup> (Refer to Power Savings with Page Mode Operation diagram)	I <sub>CC3</sub>	$V_{CC}$ =3.6 V, $V_{IN}$ = $V_{IH}$ or $V_{IL}$ Chip Enabled, $I_{OUT}$ = 0		4		mA
Read/Write Quiescent Operating Supply Current <sup>3</sup>	I <sub>CC4</sub>	$V_{CC}$ =3.6 V, $V_{IN}$ = $V_{IH}$ or $V_{IL}$ Chip Enabled, $I_{OUT}$ = 0, f = 0			3.0	mA
Maximum Standby Current <sup>3</sup>	I <sub>SB1</sub>	$V_{IN} = V_{CC}$ or 0V Chip Disabled $t_A = 85^{\circ}C$ , $V_{CC} = 3.6$ V		2.0	20	μА
Maximum Data Retention Current <sup>3</sup>	I <sub>DR</sub>	Vcc = 1.8V, $V_{IN} = V_{CC}$ or 0 Chip Disabled, $t_A = 85^{\circ}C$			10	μА

<sup>1.</sup> Typical values are measured at Vcc=Vcc Typ., T<sub>A</sub>=25°C and not 100% tested.

<sup>2.</sup> This parameter is specified with the outputs disabled to avoid external loading effects. The user must add current required to drive output capacitance expected in the actual system.

<sup>3.</sup> This device assumes a standby mode if the chip is disabled ( $\overline{\text{CE1}}$  high or CE2 low). In order to achieve low standby current all inputs must be within 0.2 volts of either VCC or VSS



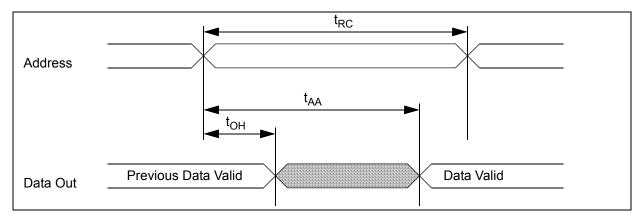
# **Timing Test Conditions**

Item	
Input Pulse Level	0.1V <sub>CC</sub> to 0.9 V <sub>CC</sub>
Input Rise and Fall Time	5ns
Input and Output Timing Reference Levels	0.5 V <sub>CC</sub>
Output Load	CL = 30pF
Operating Temperature	-40 to +85 °C

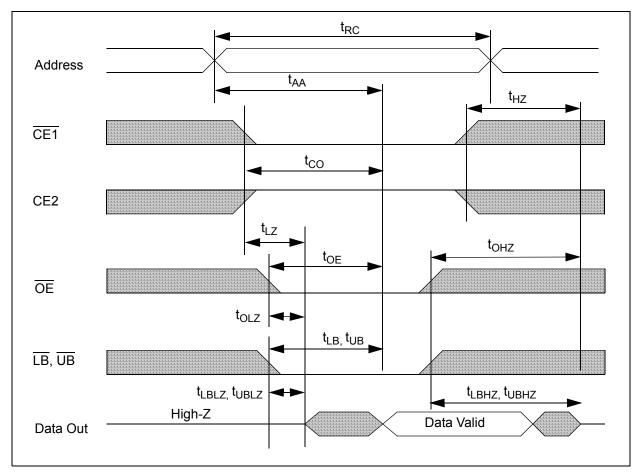
# **Timing**

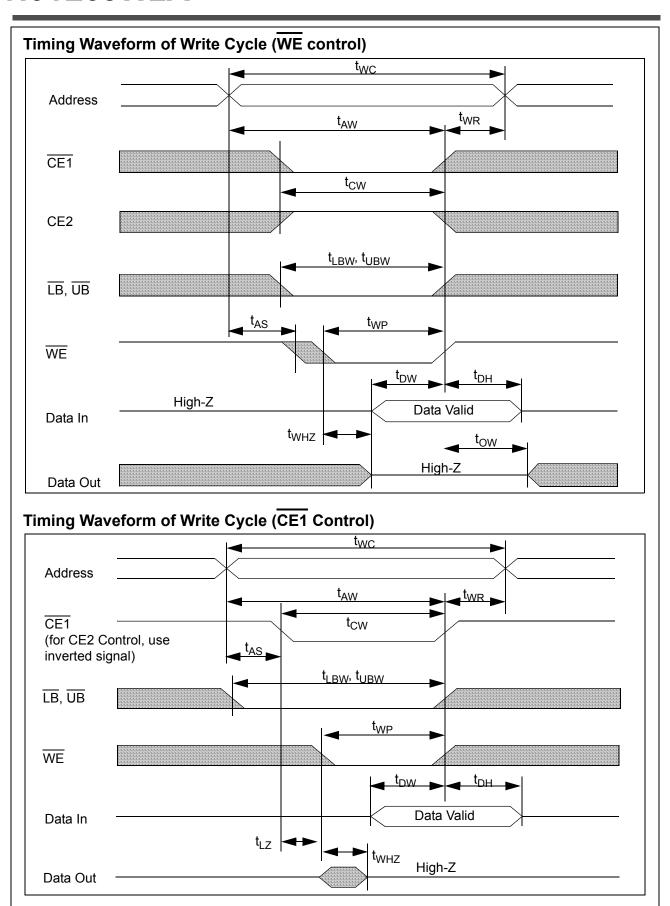
láo-ro	Comple al	2.3 -	3.6 V	2.7 -	2.7 - 3.6 V	
Item	Symbol	Min.	Max.	Min.	Max.	Units
Read Cycle Time	t <sub>RC</sub>	70		55		ns
Address Access Time	t <sub>AA</sub>		70		55	ns
Chip Enable to Valid Output	t <sub>CO</sub>		70		55	ns
Output Enable to Valid Output	t <sub>OE</sub>		35		30	ns
Byte Select to Valid Output	t <sub>LB</sub> , t <sub>UB</sub>		70		55	ns
Chip Enable to Low-Z output	t <sub>LZ</sub>	10		10		ns
Output Enable to Low-Z Output	t <sub>OLZ</sub>	5		5		ns
Byte Select to Low-Z Output	t <sub>LBZ</sub> , t <sub>UBZ</sub>	10		10		ns
Chip Disable to High-Z Output	t <sub>HZ</sub>	0	20	0	20	ns
Output Disable to High-Z Output	t <sub>OHZ</sub>	0	20	0	20	ns
Byte Select Disable to High-Z Output	t <sub>LBHZ</sub> , t <sub>UBHZ</sub>	0	20	0	20	ns
Output Hold from Address Change	t <sub>OH</sub>	10		10		ns
Write Cycle Time	t <sub>WC</sub>	70		55		ns
Chip Enable to End of Write	t <sub>CW</sub>	50		40		ns
Address Valid to End of Write	t <sub>AW</sub>	50		40		ns
Byte Select to End of Write	t <sub>LBW</sub> , t <sub>UBW</sub>	50		40		ns
Write Pulse Width	t <sub>WP</sub>	40		40		ns
Address Setup Time	t <sub>AS</sub>	0		0		ns
Write Recovery Time	t <sub>WR</sub>	0		0		ns
Write to High-Z Output	t <sub>WHZ</sub>		20		20	ns
Data to Write Time Overlap	t <sub>DW</sub>	40		35		ns
Data Hold from Write Time	t <sub>DH</sub>	0		0		ns
End Write to Low-Z Output	t <sub>OW</sub>	5		10		ns

# Timing of Read Cycle ( $\overline{CE1} = \overline{OE} = V_{IL}$ , $\overline{WE} = CE2 = V_{IH}$ )

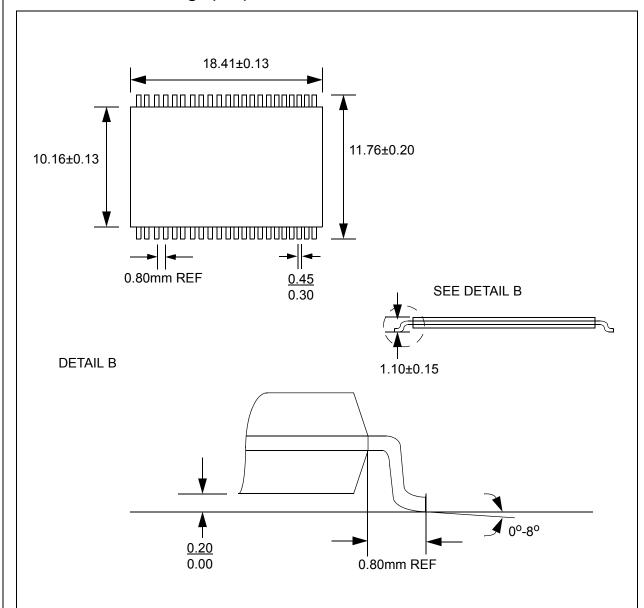


# Timing Waveform of Read Cycle (WE=V<sub>IH</sub>)





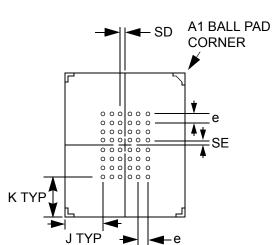
## 44-Lead TSOP II Package (T44)



#### Note:

- 1. All dimensions in inches (Millimeters)
- 2. Package dimensions exclude molding flash

# Ball Grid Array Package A1 BALL PAD CORNER (3) D 1.24±0.10 1.0.35±0.05 DIA. 2. SEATING PLANE - Z \$\display 0.15 | Z \\ \$\display 0.05 | Z\$



**BOTTOM VIEW** 

**TOP VIEW** 

1. DIMENSION IS MEASURED AT THE MAXIMUM SOLDER BALL DIAMETER. PARALLEL TO PRIMARY Z.

SIDE VIEW

- 2. PRIMARY DATUM Z AND SEATING PLANE ARE DEFINED BY THE SPHERICAL CROWNS OF THE SOLDER BALLS.
- 3. A1 BALL PAD CORNER I.D. TO BE MARKED BY INK.

## **Dimensions (mm)**

D	E		BALL MATRIX			
	<b>E</b>	SD	SE	J	K	TYPE
6±0.10	8±0.10	0.375	0.375	1.125	1.375	FULL

#### **Ordering Information**

Part Number	Package	Shipping Method
N01L63W2AT5I	Leaded 44-TSOP II	Tray
N01L63W2AT25I	Green 44-TSOP II (RoHS Compliant)	Tray
N01L63W2AB5I	Leaded 48-BGA	Tray
N01L63W2AB25I	Green 48-BGA (RoHS Compliant)	Tray
N01L63W2AT5IT	Leaded 44-TSOP II	Tape & Reel
N01L63W2AT25IT	Green 44-TSOP II (RoHS Compliant)	Tape & Reel
N01L63W2AB5IT	Leaded 48-BGA	Tape & Reel
N01L63W2AB25IT	Green 48-BGA (RoHS Compliant)	Tape & Reel

#### **Revision History**

Revision	Date	Change Description
Α	Jan 2001	Initial preliminary release
В	Mar 2001	Corrected Figure 1: TSOP Pin Configuration, pins 18-22. Modified $I_{CC3}$ , figure 8, other minor edits
С	April 2001	Modified timing table, changed access time to 55 ns
D	Dec. 2001	Part number change from EM064J16, modified Overview and Features, Added Page Mode Operation diagram, revised Operating Characteristics table, Functional Description table and Ordering Information diagram
E	Nov. 2002	Replaced Isb and Icc on Product Family table with typical values
F	Oct. 2004	Added Pb-Free and Green Package Option
G	Nov. 2005	Removed Pb-Free Pkg, added Green Pkg and RoHS Compliant
Н	September 2006	Converted to AMI Semiconductor
9	July 2008	Converted to ON Semiconductor and new part numbers

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